

“Y / Descriptions

SOT-23 NPN Silicon NPN transistor in a SOT-23 Plastic Package.

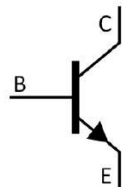
• Ė / Features

S8550MG
Complementary pair with S8550MG,HF Product.

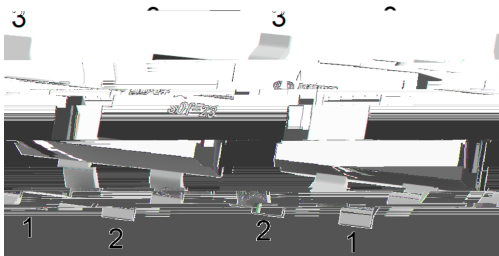
v / Applications

Power amplifier applications.

л ~ α ÷ / Equivalent Circuit



ã λ ũ / Pinning



PIN1 Base PIN 2 Emitter PIN 3 Collector

ǎ z z Ł. H Ć / h_{FE} Classifications & Marking

h _{FE} Classifications Symbol	B	C	D
h _{FE(1)} Range	85 160	120 200	160 300
Marking	GY3B	GY3C	GY3D

绝对最大额定值(Absolute Maximum Ratings)(Ta=25℃)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V _{CBO}	40	V
Collector to Emitter Voltage	V _{CEO}	25	V
Emitter to Base Voltage	V _{EBO}	6.0	V
Collector Current	I _C	800	mA
Base Current	I _B	200	mA
Collector Power Dissipation	P _C	200	mW
Junction Temperature	T _j	150	
Storage Temperature Range	T _{stg}	-55 ~ 150	

电 气 特 性 (Electrical Characteristics)(Ta=25℃)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Base Breakdown Voltage	V _{CBO}	I _C =0.1mA I _E =0	40			V
Collector to Emitter Breakdown Voltage	V _{CEO}	I _C =2.0mA I _B =0	25			V
Emitter to Base Breakdown Voltage	V _{EBO}	I _E =0.1mA I _C =0	6.0			V
Collector Cut-Off Current	I _{CBO}	V _{CB} =35V I _E =0			0.1	μA
Emitter Cut-off Current	I _{EBO}	V _{EB} =6.0V I _C =0			0.1	μA
DC Current Gain	h _{FE(1)}	V _{CE} =1.0V I _C =100mA	85		300	
	h _{FE(2)}	V _{CE} =1.0V I _C =500mA	40			
	h _{FE(3)}	V _{CE} =1.0V I _C =5.0mA	45			
Collector-Emitter Saturation Voltage	V _{CE(sat)}	I _C =500mA I _B =50mA		0.28	0.5	V
Base-Emitter Saturation Voltage	V _{BE(sat)}	I _C =500mA I _B =50mA		0.98	1.2	V
Base-Emitter Voltage	V _{BE}	V _{CE} =1.0V I _C =10mA		0.66	1.0	V
Transition Frequency	f _T	V _{CE} =10V I _C =50mA	100	190		MHz
Collector Output Capacitance	C _{ob}	V _{CB} =10V I _E =0 f=1.0MHz		9.0		pF

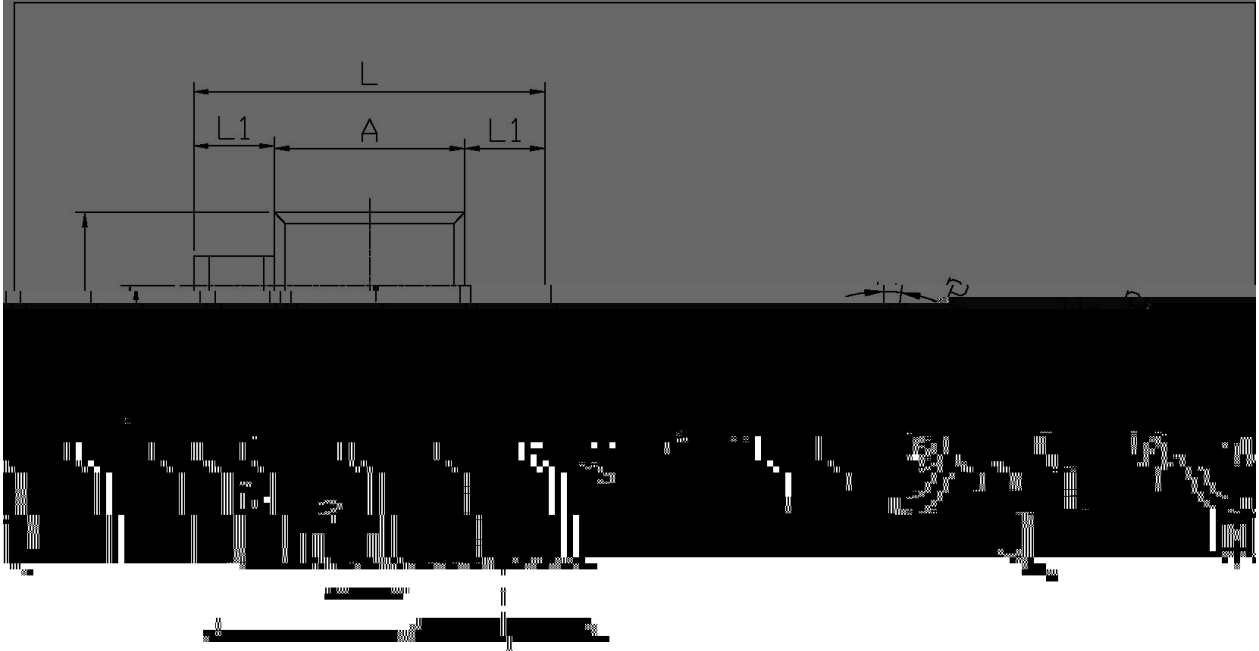
S8050MG

Rev.I May.-2023

Ⓢ Ⓜ Ⓛ Ⓡ / Package Dimensions

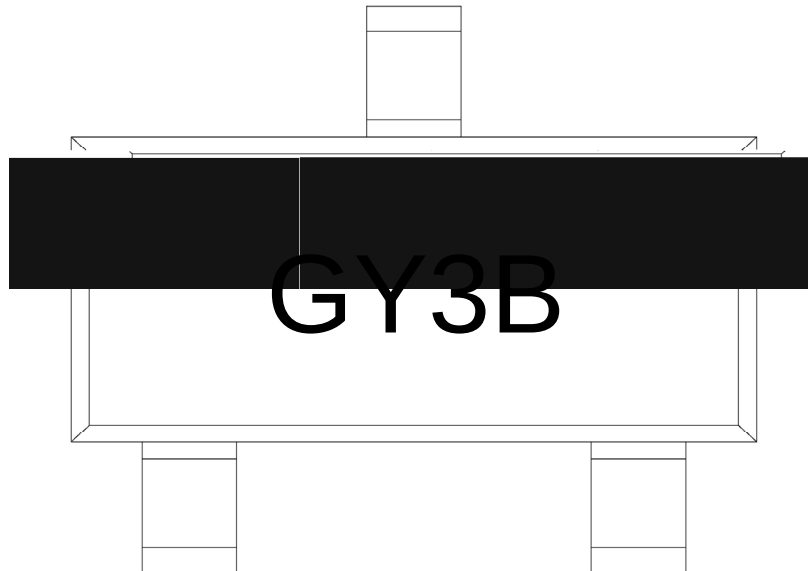
SOT-23

单位: mm



Date	Time	Location	Remarks
10/10/2018	10:00	1000m	1000m
10/10/2018	10:00	1000m	1000m
10/10/2018	10:00	1000m	1000m
10/10/2018	10:00	1000m	1000m
10/10/2018	10:00	1000m	1000m
10/10/2018	10:00	1000m	1000m
10/10/2018	10:00	1000m	1000m

1. 标记 / Marking Instructions



G

Y3

B h_{FE}

Note:

G HF Product Code

Y3 Product Type Code

B h_{FE} Classifications Symbol Code

测试条件 / Whp shudwxuh Suriloh i ru LU Uhi or z Vroghulq j+Se0l uhh,

- 1

150 180

60 90sec;

1.Preheating:150~180 , Time:60~90sec.
- 2

245±5

5±0.5sec;

2.Peak Temp.:245±5 , Duration:5±0.5sec.
- 3